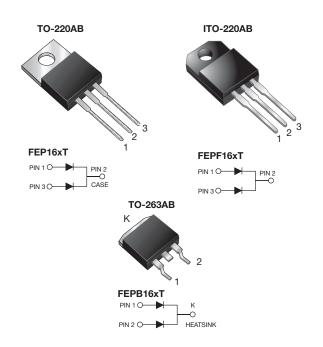
FEP16xT, FEPF16xT, FEPB16xT

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RoHS

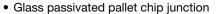
Dual Common Cathode Ultrafast Plastic Rectifier

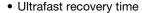


PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 8.0 A					
V_{RRM}	50 V to 600 V					
I _{FSM}	200 A, 125 A					
t _{rr}	35 ns, 50 ns					
V _F	0.95 V, 1.30 V, 1.50 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB					
Diode variations	Common cathode					

FEATURES

Power pack





- · Low switching losses, high efficiency
- High forward surge capability
- AEC-Q101 qualified
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	FEP16AT	EP16AT FEP16BT FEP16CT FEP16DT FEP16FT FEP16GT FEP16HT FEP16J							
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	٧
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current at T _C = 100 °C	I _{F(AV)}		16							
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	200 125								А
Operating storage and temperature range	T _J , T _{STG}	-55 to +150							°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500							٧	



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)												
PARAMETER	TEST CONDITIONS		SYMBOL	FEP 16AT	FEP 16BT	FEP 16CT	FEP 16DT	FEP 16FT	FEP 16GT	FEP 16HT	FEP 16JT	UNIT
Maximum instantaneous forward voltage per diode	8.0 A		V _F ⁽¹⁾	0.95			1.30		1.50		V	
Maximum DC reverse current per diode at rated DC		T _C = 25 °C	· I _R	10							μA	
blocking voltage		T _C = 100 °C	'K	500							μ, τ	
Maximum reverse recovery time per diode	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	35 50				0		ns		
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	85			6	0	pF			

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)									
PARAMETER SYMBOL FEP FEPB L									
Typical thermal resistance from junction to case per diode	$R_{ heta JC}$	2.2	3.1	2.2	°C/W				

ORDERING INFORMATION (Example)									
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
TO-220AB	FEP16JT-E3/45	1.85	45	50/tube	Tube				
ITO-220AB	FEPF16JT-E3/45	1.97	45	50/tube	Tube				
TO-263AB	FEPB16JT-E3/45	1.35	45	50/tube	Tube				
TO-263AB	FEPB16JT-E3/81	1.35	81	800/reel	Tape and reel				
TO-220AB	FEP16JTHE3/45 (1)	1.85	45	50/tube	Tube				
ITO-220AB	FEPF16JTHE3/45 ⁽¹⁾	1.97	45	50/tube	Tube				
TO-263AB	FEPB16JTHE3/45 (1)	1.35	45	50/tube	Tube				
TO-263AB	FEPB16JTHE3/81 ⁽¹⁾	1.35	81	800/reel	Tape and reel				

Note

⁽¹⁾ AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

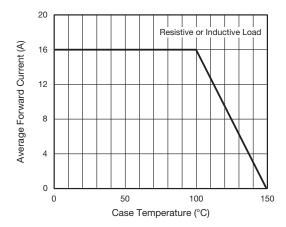


Fig. 1 - Forward Current Derating Curve

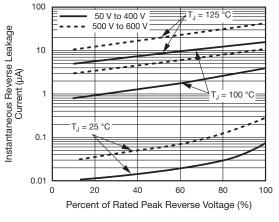


Fig. 4 - Typical Reverse Characteristics Per Diode

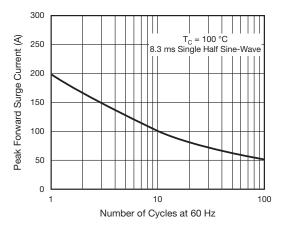


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

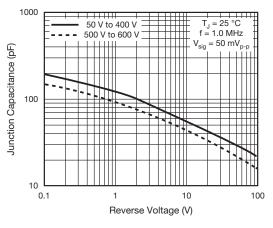


Fig. 5 - Typical Junction Capacitance Per Diode

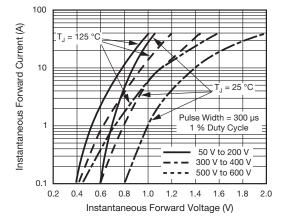


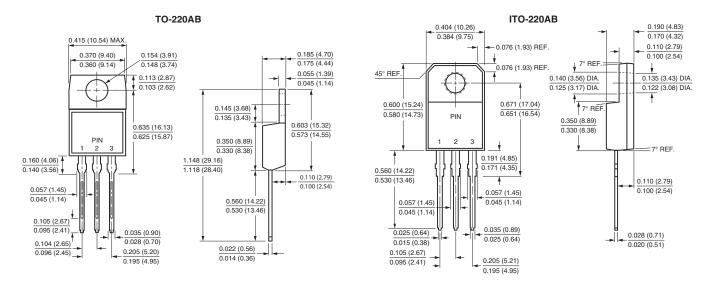
Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

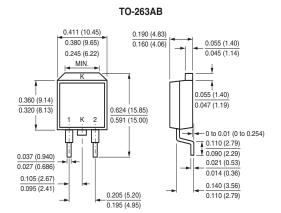


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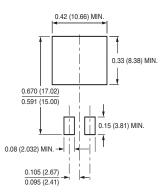
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Mounting Pad Layout





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